L	Hits	Search Text	DB	Time stamp
Number	11070		VIGD N	2004/06/01
1	11872	(resistance or resistivity) with silicide	USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:30
2	1131	((resistance or resistivity) with silicide) with electric\$4	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:31
3	705978	electrical adj resistivity of silicide	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01
4	94	electrical adj resistivity with silicide	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:51
5	4	(aluminum adj silicide) same tantalum same (resistivity or resistance)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:36
6	11	(aluminum adj silicide) with (resistivity or resistance)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:39
7	4600	tantalum with (resistivity or resistance)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:37
8	260	(tantalum with (resistivity or resistance)) with electrical	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:37
9	494	aluminum with silicide with (resistivity or resistance)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:39
10	52	(aluminum with silicide with (resistivity or resistance)) with electric\$4	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:39
11	611	electrical adj resistivity with silicon	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:51
12	41	electrical adj resistivity adj silicon	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:52
-	2	6303415.pn.	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/06/01 15:29
_	2052	tft and crystalliz\$5 and gate and source and drain	DERWENT USPAT; US-PGPUB; EPO; JPO;	2002/12/04 16:12
-	704	(tft and crystalliz\$5 and gate and source and drain) and cataly\$3	DERWENT USPAT; US-PGPUB; EPO; JPO;	2002/12/04 14:40
_	576	((tft and crystalliz\$5 and gate and source and drain) and cataly\$3) and (active adj layer)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2002/12/04 14:41
_	270	(((tft and crystalliz\$5 and gate and source and drain) and cataly\$3) and (active adj layer)) and getter\$3	DERWENT USPAT; US-PGPUB; EPO; JPO;	2002/12/04 14:46
	<u> </u>		DERWENT	<u> </u>

-	212	((((tft and crystalliz\$5 and gate and	USPAT;	2002/12/04
		source and drain) and cataly\$3) and	US-PGPUB;	14:48
		(active adj layer)) and getter\$3) and	EPO; JPO;	
	_	tantalum and nickel	DERWENT	
-	5	((((tft and crystalliz\$5 and gate and	USPAT;	2002/12/04
		source and drain) and cataly\$3) and	US-PGPUB;	16:13
		(active adj layer)) and getter\$3) and	EPO; JPO;	
İ	202	tantalum and nickel) and @ad<19970610	DERWENT	2002/12/04
-	303	<pre>(crystalliz\$5 same silicon same cataly\$3) and getter\$3</pre>	USPAT; US-PGPUB;	2002/12/04
		and getterss	EPO; JPO;	16.13
İ			DERWENT	
_	24	((crystalliz\$5 same silicon same	USPAT;	2002/12/06
		cataly\$3) and getter\$3) and @ad<19970610	US-PGPUB;	11:32
			EPO; JPO;	
			DERWENT	
-	2	5550070.pn.	USPAT;	2002/12/04
		·	US-PGPUB;	17:10
			EPO; JPO;	
	_		DERWENT	
-	6		USPAT	2002/12/04
		"5330935" "5403772" "5426064").PN.	iicham	17:45 2002/12/04
-	44	5550070.URPN.	USPAT	18:06
_	168	phosphorus same nickel same getter\$3	USPAT;	2002/12/06
"	100	phosphorus same nicker same getter;	US-PGPUB;	11:31
			EPO; JPO;	
			DERWENT	
_	19	(phosphorus same nickel same getter\$3)	USPAT;	2002/12/06
		and @ad<19970610	US-PGPUB;	12:01
•			EPO; JPO;	!
			DERWENT	
-	2005	gate with tantalum	USPAT;	2002/12/06
			US-PGPUB;	12:00
1			EPO; JPO;	1
			DERWENT	2000/10/06
-	840	(gate with tantalum) and @ad<19970610	USPAT;	2002/12/06
			US-PGPUB;	13:45
	ĺ		EPO; JPO; DERWENT	
_	31	((gate with tantalum) and @ad<19970610)	USPAT;	2002/12/06
]	and crystalliz\$5 and cataly\$3	US-PGPUB;	13:35
		and orgonarrage and oasarges	EPO; JPO;	
			DERWENT	
-	148	(nickel or ni) with (source or drain)	USPAT;	2002/12/06
		with channel	US-PGPUB;	14:48
			EPO; JPO;	
		[, , , , , , , , , , , , , , , , , , ,	DERWENT	
-	20	, , , , , , , , , , , , , , , , , , , ,	USPAT;	2002/12/06
		with channel) with concentration	US-PGPUB;	13:37
			EPO; JPO; DERWENT	
1_	74	((nickel or ni) with (source or drain)	USPAT;	2002/12/06
	, ,	with channel) and @ad<19970610	US-PGPUB;	14:15
			EPO; JPO;	
			DERWENT	
-	149	cataly\$3 with channel with less	USPAT;	2002/12/06
			EPO; JPO;	14:21
1			DERWENT	
-	109	(cataly\$3 with channel with less) and	USPAT;	2002/12/06
		@ad<19970610	US-PGPUB;	14:16
			EPO; JPO;	
_	47	((antalyes with abannal with lace) and	DERWENT	2002/12/06
_	4/	((cataly\$3 with channel with less) and @ad<19970610) and (nickel or ni)	USPAT; US-PGPUB;	14:16
		Gad/199/0010 and (HICKET OF HI)	EPO; JPO;	17.10
			DERWENT]
-	0	(cataly\$3 with channel with less) and	USPAT;	2002/12/06
		"5.times.10.sup.16."	EPO; JPO;	14:21
		•	DERWENT	
				•

_	3	(ni or nickel) with channel with	USPAT;	2002/12/06
		"5.times.10.sup.16"	EPO; JPO;	14:23
		-	DERWENT	
_	0	(ni or fe or co or pd or pt or cu or au)	USPAT;	2002/12/06
		with channel with "5.times.10.sup.16"	EPO; JPO;	14:25
		with channel with 5.times.10.sup.10	DERWENT	14.25
-	3	(nickel or iron or gold or copper or	USPAT;	2002/12/06
		platinum or palladium or cobalt) with	EPO; JPO;	14:26
		channel with "5.times.10.sup.16"	DERWENT	
-	0	(nickel or iron or gold or copper or	USPAT;	2002/12/06
1	_	platinum or palladium or cobalt) with	EPO; JPO;	14:26
		channel with "5.times.10.sup.15"	DERWENT	11.20
ŀ				2002/12/06
- .	0	(nickel or iron or gold or copper or	USPAT;	2002/12/06
		platinum or palladium or cobalt) with	EPO; JPO;	14:26
		channel with "5.times.10.sup.14"	DERWENT	
-	1	(nickel or iron or gold or copper or	USPAT;	2002/12/06
		platinum or palladium or cobalt) with	EPO; JPO;	14:26
		channel with "5.times.10.sup.17"	DERWENT	
i _	5	(nickel or iron or gold or copper or	USPAT;	2002/12/06
-	3			1
		platinum or palladium or cobalt) with	EPO; JPO;	14:31
		channel with "1.times.10.sup.16"	DERWENT	
-	0	(nickel or iron or gold or copper or	USPAT;	2002/12/06
		platinum or palladium or cobalt) with	EPO; JPO;	14:45
		channel with "1.times.10.sup.15"	DERWENT	
-	2	6303415.pn.	USPAT;	2002/12/06
	1		EPO; JPO;	14:45
			DERWENT	
		1 1 1	L	2002/12/06
-	77	(nickel or ni) same (source or drain)	USPAT;	1
		same channel same order\$1	US-PGPUB;	14:51
			EPO; JPO;	
			DERWENT	
_	16	((nickel or ni) same (source or drain)	USPAT;	2002/12/06
1	**	same channel same order\$1) same	US-PGPUB;	14:51
		concentration	EPO; JPO;	1
		Concentration		
	_	5550050	DERWENT	2002/12/06
-	2	5550070.pn.	USPAT;	2002/12/06
			US-PGPUB;	17:32
			EPO; JPO;	
			DERWENT	
_	370	(interlayer with insulat\$3 with silicon	USPAT;	2003/06/06
		with nitride) and (interlayer with	US-PGPUB;	12:32
		insulat\$3 with (acrylic or polyimide or	EPO; JPO;	
			DERWENT	
		polyamide or epoxy or epoxies)) and gate		2002/06/06
-	37	((interlayer with insulat\$3 with silicon	USPAT;	2003/06/06
		with nitride) and (interlayer with	US-PGPUB;	12:33
1		insulat\$3 with (acrylic or polyimide or	EPO; JPO;	
		polyamide or epoxy or epoxies)) and gate)	DERWENT ·	
		and @ad<19970610		
-	2		USPAT;	2003/09/30
	1	0000070.pii.	US-PGPUB;	20:08
1	1		EPO; JPO;	
1			1	
			DERWENT	2002/12/00
-	2258	silicon with (nickel or ni) with	USPAT;	2003/12/08
		(crystallization or crystaliz\$3 or	US-PGPUB;	18:16
		amorphous)	EPO; JPO;	
			DERWENT	
-	968	(silicon with (nickel or ni) with	USPAT;	2003/12/08
		(crystallization or crystaliz\$3 or	US-PGPUB;	18:42
	1	amorphous)) and @ad<19970610	EPO; JPO;	
1	1	amorphous, , and ead(19970010	DERWENT	
1	1			1 2002 /12 /09
-	67	(silicon with (nickel or ni) with	USPAT;	2003/12/08
		(crystallization or crystaliz\$3 or	US-PGPUB;	15:28
		amorphous)) same source same drain same	EPO; JPO;	
1		gate	DERWENT]
-	17		USPAT;	2003/12/08
1]	(crystallization or crystaliz\$3 or	US-PGPUB;	16:14
		amorphous)) same source same drain same	EPO; JPO;	
		gate) and @ad<19970610	DERWENT	2002/12/09
[-	6		USPAT	2003/12/08
		"5330935" "5403772" "5426064").PN.	1	15:38
-	54	5550070.URPN.	USPAT	2003/12/08
1	1			16:13

-	1	((silicon with (nickel or ni) with	USPAT;	2003/12/08
		(crystallization or crystaliz\$3 or	US-PGPUB;	16:16
		amorphous)) same source same drain same	EPO; JPO;	
		gate) and (concentration with nickel with	DERWENT	
	_	(source or drain) with channel)	TICDAM.	2003/12/08
-	6	((silicon with (nickel or ni) with	USPAT; US-PGPUB;	16:32
		(crystallization or crystaliz\$3 or	EPO; JPO;	10.32
		amorphous)) same source same drain same gate) and (concentration same nickel same	DERWENT	
		(source or drain) same channel)	DEKMENI	
_	1	((silicon with (nickel or ni) with	USPAT;	2003/12/08
		(crystallization or crystaliz\$3 or	US-PGPUB;	18:17
	1	amorphous)) same source same drain same	EPO; JPO;	10.17
	[gate) and (concentration same (iron or	DERWENT	
}		palladium or copper) same (source or	, , , , , , , , , , , , , , , , , , , ,	
		drain) same channel)		
_	1	((silicon with (nickel or ni) with	USPAT;	2003/12/08
	_	(crystallization or crystaliz\$3 or	US-PGPUB;	16:33
		amorphous)) same source same drain same	EPO; JPO;	
		gate) and (concentration same iron same	DERWENT	
		(source or drain) same channel)		
-	6	(silicon with (nickel or ni) with	USPAT;	2003/12/08
	1	(crystallization or crystaliz\$3 or	US-PGPUB;	17:00
1	ł	amorphous)) and (concentration same	EPO; JPO;	
	1	(iron or palladium or copper) same	DERWENT	
İ		(source or drain) same channel)		
-	171	(silicon with (nickel or ni) with	USPAT;	2003/12/08
		(crystallization or crystaliz\$3 or	US-PGPUB;	17:00
İ		amorphous)) and (phosphorus with	EPO; JPO;	[
	1	getter\$3 with nickel)	DERWENT	0000 /40 /00
	2	((silicon with (nickel or ni) with	USPAT;	2003/12/08
		(crystallization or crystaliz\$3 or	US-PGPUB;	17:05
		amorphous)) and (phosphorus with	EPO; JPO;	
		getter\$3 with nickel)) and @ad<19970610	DERWENT	2002/12/00
-	19	((silicon with (nickel or ni) with	USPAT;	2003/12/08
		(crystallization or crystaliz\$3 or	US-PGPUB;	17:11
		amorphous)) and (phosphorus with	EPO; JPO; DERWENT	
	96	getter\$3 with nickel)) and @ad<19980610	USPAT;	2003/12/08
1 -	1	(silicon with (nickel or ni) with (crystallization or crystaliz\$3 or	US-PGPUB;	17:12
		amorphous)) and (nickel with source with	EPO; JPO;	11.16
		drain with channel)	DERWENT	
_	24	((silicon with (nickel or ni) with	USPAT;	2003/12/08
	24	(crystallization or crystaliz\$3 or	US-PGPUB;	17:12
		amorphous)) and (nickel with source with	EPO; JPO;	
		drain with channel)) and @ad<19970610	DERWENT	
]_	14	("5147826" "5275851" "5481121"	USPAT	2003/12/08
		"5492843" "5501989" "5529937"		17:21
	1	"5534716" "5543352" "5550070"		
		"5580792" "5585291" "5612250"		
İ	1	"5643826" "5654203").PN.		
-	1370	silicon with iron with (crystallization	USPAT;	2003/12/08
	1	or crystaliz\$3 or amorphous)	US-PGPUB;	18:16
	1	_	EPO; JPO;	
	1		DERWENT	
-	3	(silicon with iron with (crystallization	USPAT;	2003/12/08
		or crystaliz\$3 or amorphous)) and	US-PGPUB;	18:41
		(concentration same (iron or palladium or	EPO; JPO;	
		copper) same (source or drain) same	DERWENT	
		channel)		
-	6	,	USPAT;	2003/12/08
		palladium or copper) with source with	US-PGPUB;	18:42
		drain with channel) and @ad<19970610	EPO; JPO;	
			DERWENT	2002/12/00
-	30	concentration with (nickel or iron or	USPAT;	2003/12/08
		palladium or copper) with source with	US-PGPUB;	20:13
		drain with channel	EPO; JPO;	
1	<u> </u>		DERWENT	l

_					
Г	-	19	("5244819" "5534716" "5608232"	USPAT	2003/12/08
			"5616506" "5639698" "5643826"		18:48
			"5700333" "5736438" "5773309"		
			"5773329" "5821138" "5834071"		
			"5834345" "5869363" "5879977"		
			"5897347" "5923962" "5956579"		
		İ	"6087245").PN.		
	- !	0	concentration with nickel with source	USPAT;	2003/12/08
ĺ			with drain with channel with magnitude	US-PGPUB;	20:16
				EPO; JPO;	
				DERWENT	
	_	29	concentration with nickel with source	USPAT;	2003/12/08
			with drain with channel	US-PGPUB;	20:14
				EPO; JPO;	
	1			DERWENT	
	_	0	nickel with source with drain with	USPAT;	2003/12/08
			channel with magnitude	US-PGPUB;	20:17
			,	EPO; JPO;	
				DERWENT	
	_	4	nickel with source with drain with	USPAT;	2003/12/08
			channel with (double or times)	US-PGPUB;	20:17
		:		EPO; JPO;	
ı				DERWENT	
1	_	2	nickel with source with drain with	USPAT;	2003/12/08
		-	channel with higher	US-PGPUB;	20:18
			onamici wion nighter	EPO; JPO;	
				DERWENT	
	_	6	nickel with source with drain with	USPAT;	2003/12/08
		Ŭ	channel with lower	US-PGPUB;	20:25
ŀ				EPO; JPO;	
				DERWENT	
-	_	165	nickel with channel with concentration	USPAT;	2003/12/08
		100		US-PGPUB;	20:25
1				EPO; JPO;	
				DERWENT	
	_	34	(nickel with channel with concentration)	USPAT;	2003/12/08
		24	and @ad<19970610	US-PGPUB;	20:26
			and Gad(155/0010	EPO; JPO;	
				DERWENT	
	_	9019939	((nickel with channel with concentration)	USPAT;	2003/12/08
İ	_	3013333	and @ad<19970610) no (energy adj	US-PGPUB;	20:26
			laboratory)	EPO; JPO;	
			Tabolacoly;	DERWENT	
- 1				LDDVAMBLI	I